## NSN 5961-01-081-3431

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-081-3431 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.667 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 325.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 21908-167-0043-001 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**